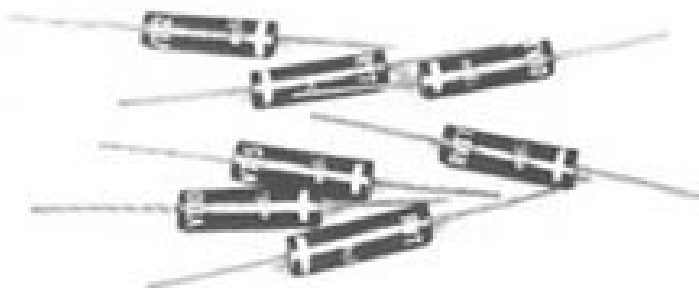




VT RVT

HIGH VOLTAGE 50 mA SILICON RECTIFIERS

- SMALL SIZE MOLDED PACKAGE
- PRV 10,000 TO 15,000 VOLTS
- FAST RECOVERY (R_SERIES)
- AVALANCHE CHARACTERISTICS
- LOW LEAKAGE



EDI Type	PRV Volts	REVERSE RECOVERY TIME (Fig.4)
VT1000	10,000	-
VT1200	12,000	-
VT1500	15,000	-
RVT1000	10,000	100 ns max.
RVT1200	12,000	100 ns max.
RVT1500	15,000	100 ns max.

ELECTRICAL CHARACTERISTICS (at $T_A = 25^\circ\text{C}$ Unless Otherwise Specified)

Average Rectified Forward Current @ 50°C , I_o	50 mA
Max. Peak Surge Current, I_{FSM} (8.3ms)	5 Amp
Max. Forward Voltage Drop @ 50mA, V_F	28Volts
Max. DC Reverse Current @ PRV and 25°C , I_R	1 μA
Max. DC Reverse Current @ PRV and 100°C , I_R	25 μA
Ambient Operating Temperature Range, T_A	-55 to + 125°C
Storage Temperature Range, T_{STG}	-55 to + 150°C

NOTES:

1. It is recommended that a proper heat sink be used on the terminals of this device between the body and soldering point to prevent damage from excess heat.
2. If operated over 10,000v/inch in length, devices should be immersed in oil or re - encapsulated.

EDI reserves the right to change these specifications at any time without notice.

VT RVT

FIG.1

OUTPUT CURRENT vs AMBIENT TEMPERATURE

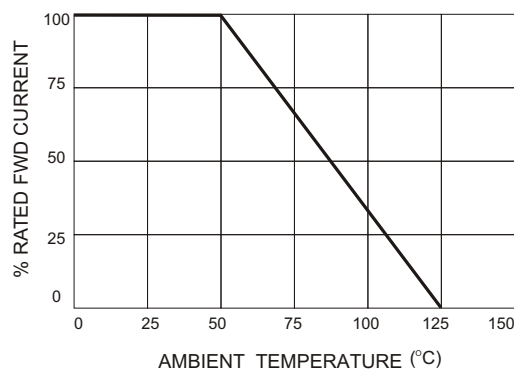


FIG.2

NON-REPETITIVE SURGE CURRENT

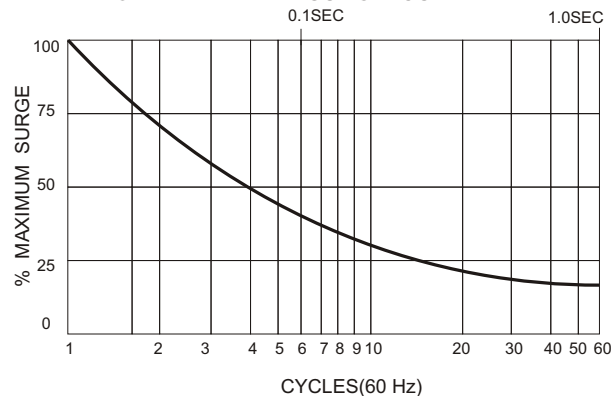
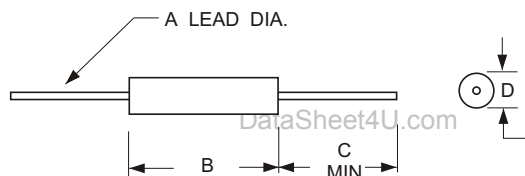


FIG.3

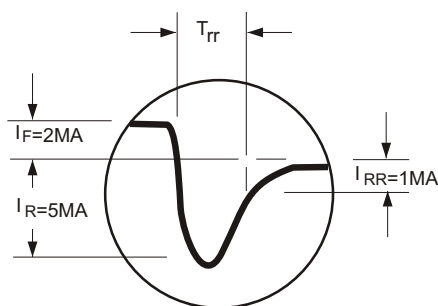
MECHANICAL
Leads-solid silverMarkings-Cathode band
and device type

	INCHES	MM
A	0.02	0.5
B	0.60	15.2
C	0.50	12.7
D	0.16	4.0

FIG.4

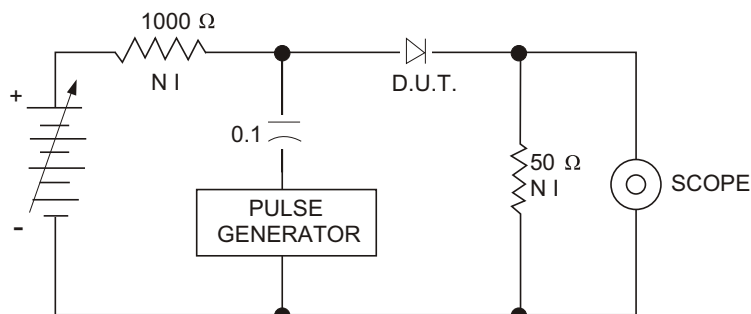
REVERSE RECOVERY TEST METHOD

RECOVERY WAVE FORM



WAVE FORMS

RECOVERY WAVE FORM



CIRCUIT

ELECTRONIC DEVICES, INC. DESIGNERS AND MANUFACTURERS OF SOLID STATE DEVICES SINCE 1951.

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